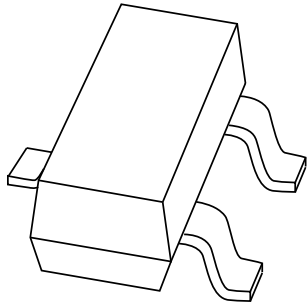


DATA SHEET



BF862

N-channel junction FET

Product specification
Supersedes data of 1999 Jun 29

2000 Jan 05



N-channel junction FET

BF862

FEATURES

- High transition frequency for excellent sensitivity in AM car radios
- High transfer admittance.

APPLICATIONS

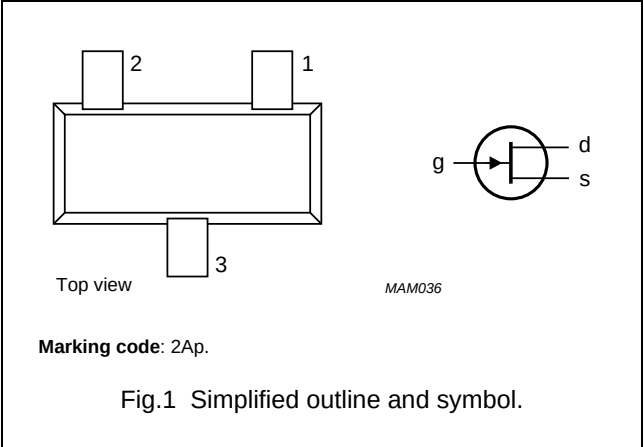
- Pre-amplifiers in AM car radios.

DESCRIPTION

Silicon N-channel symmetrical junction field-effect transistor in a SOT23 package. Drain and source are interchangeable.

PINNING SOT23

PIN	DESCRIPTION
1	source
2	drain
3	gate



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{DS}	drain-source voltage		–	–	20	V
V_{GSoff}	gate-source cut-off voltage		–0.3	–0.8	–1.2	V
I_{DSS}	drain-source current		10	–	25	mA
P_{tot}	total power dissipation	$T_s \leq 90\text{ }^{\circ}\text{C}$	–	–	300	mW
$ y_{fs} $	transfer admittance		35	45	–	mS
T_j	junction temperature		–	–	150	$^{\circ}\text{C}$

CAUTION
This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling.

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage		–	20	V
V _{DG}	drain-gate voltage		–	20	V
V _{GS}	gate-source voltage		–	–20	V
I _{DS}	drain-source current		–	40	mA
I _G	forward gate current		–	10	mA
P _{tot}	total power dissipation	T _s ≤ 90 °C; note 1	–	300	mW
T _{stg}	storage temperature		–65	+150	°C
T _j	junction temperature		–	150	°C

Note

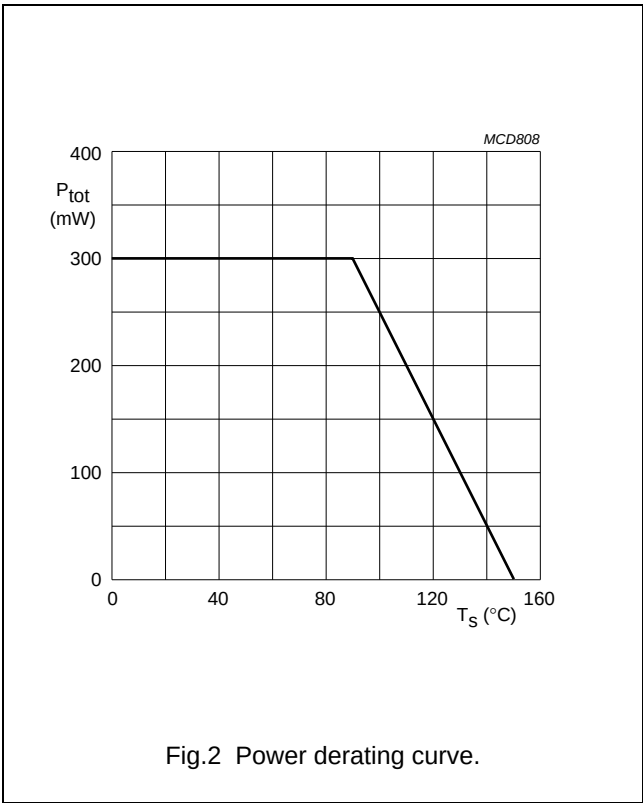
1. Main heat transfer is via the gate lead.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point	note 1	200	K/W

Note

1. Soldering point of the gate lead.



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STATIC CHARACTERISTICS

 $T_j = 25\text{ }^{\circ}\text{C}$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)GSS}$	gate-source breakdown voltage	$I_{GS} = -1\text{ }\mu\text{A}$; $V_{DS} = 0$	-20	—	—	V
V_{GS}	gate-source forward voltage	$V_{DS} = 0$; $I_G = 1\text{ mA}$	—	—	1	V
V_{GSoff}	gate-source cut-off voltage	$V_{DS} = 8\text{ V}$; $I_D = 1\text{ }\mu\text{A}$	-0.3	-0.8	-1.2	V
I_{GSS}	reverse gate current	$V_{GS} = -15\text{ V}$; $V_{DS} = 0$	—	—	-1	nA
I_{DSS}	drain-source current	$V_{GS} = 0$; $V_{DS} = 8\text{ V}$	10	—	25	mA

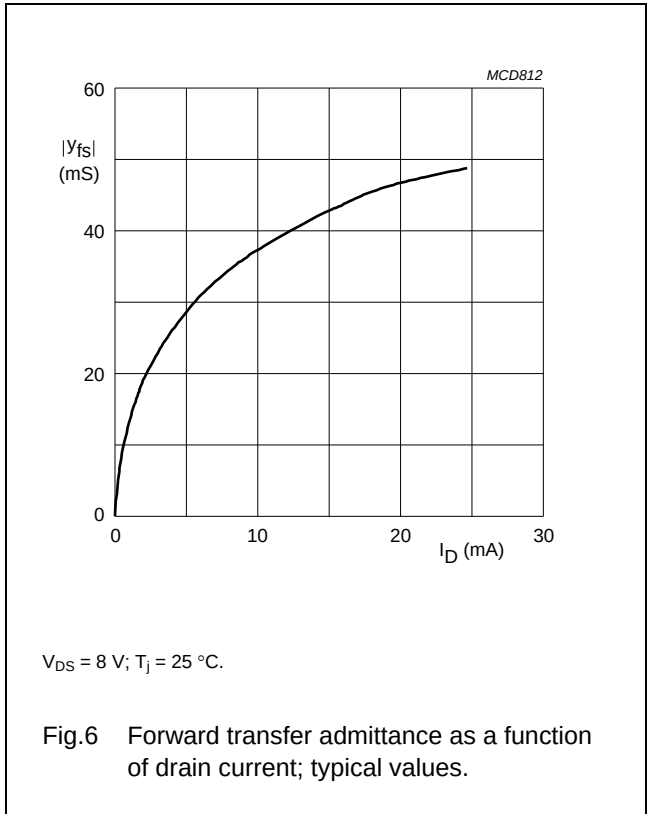
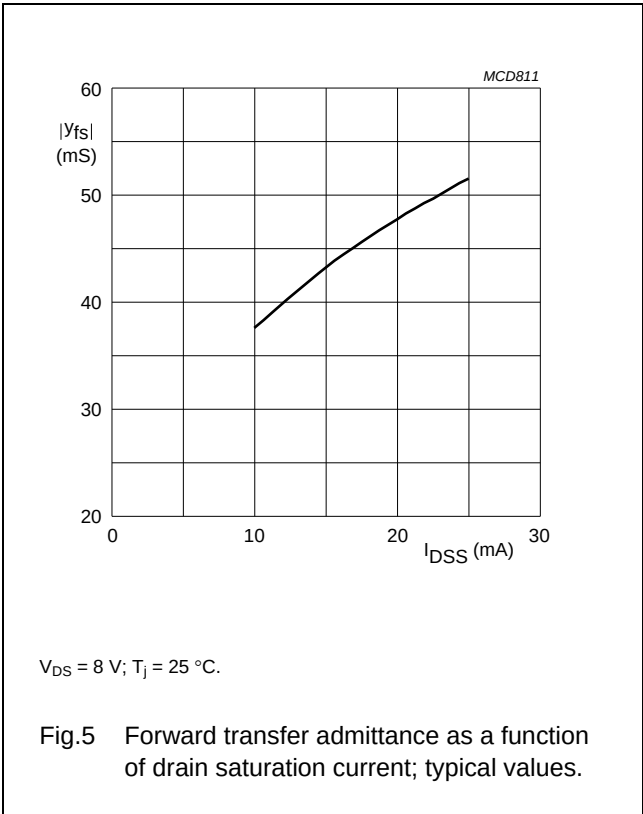
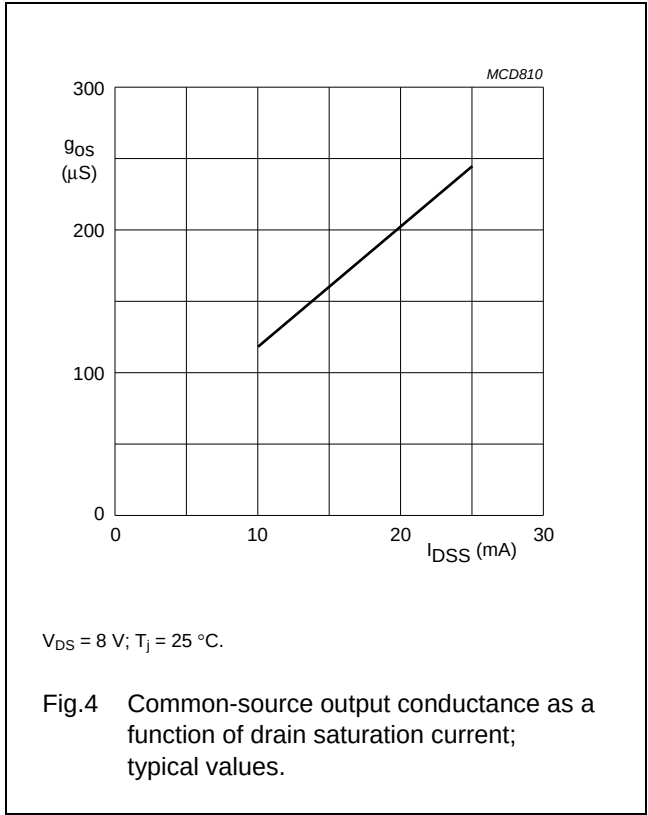
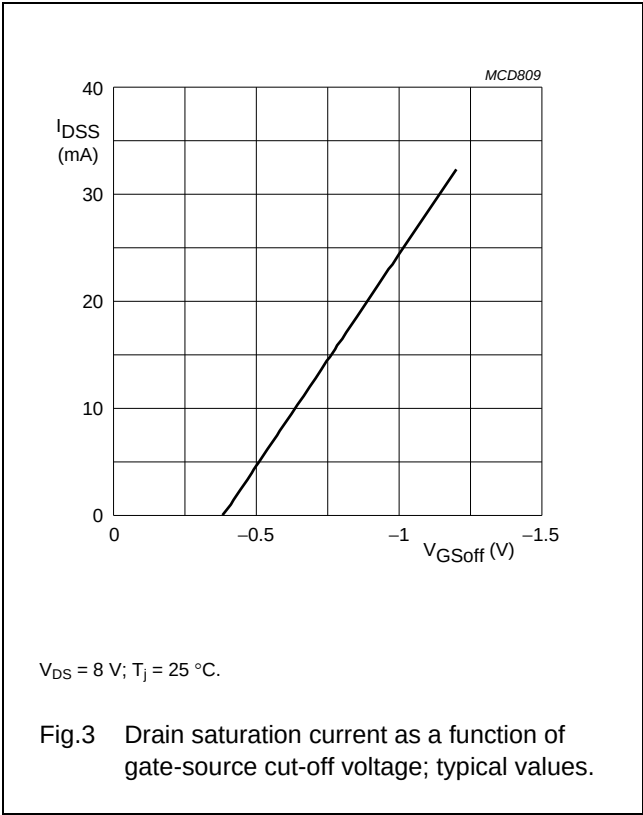
DYNAMIC CHARACTERISTICS

Common source; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{GS} = 0$; $V_{DS} = 8\text{ V}$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$ y_{fs} $	common source forward transfer admittance	$T_j = 25\text{ }^{\circ}\text{C}$	35	45	—	mS
g_{os}	common source output conductance	$T_j = 25\text{ }^{\circ}\text{C}$	—	180	400	μS
C_{iss}	input capacitance	$f = 1\text{ MHz}$	—	10	—	pF
C_{rss}	reverse transfer capacitance	$f = 1\text{ MHz}$	—	1.9	—	pF
e_n	equivalent noise input voltage	$f = 100\text{ kHz}$	—	0.8	—	$\text{nV}/\sqrt{\text{Hz}}$
f_T	transition frequency		—	715	—	MHz

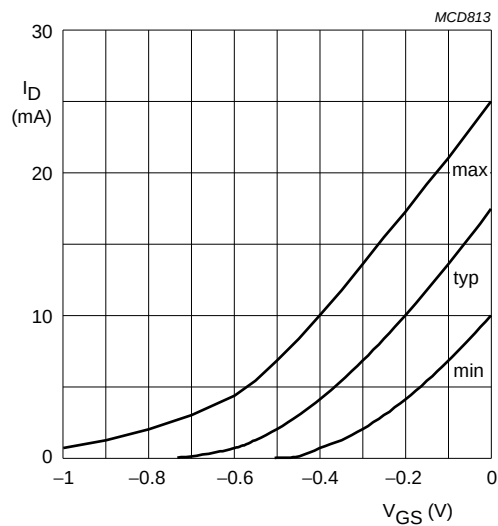
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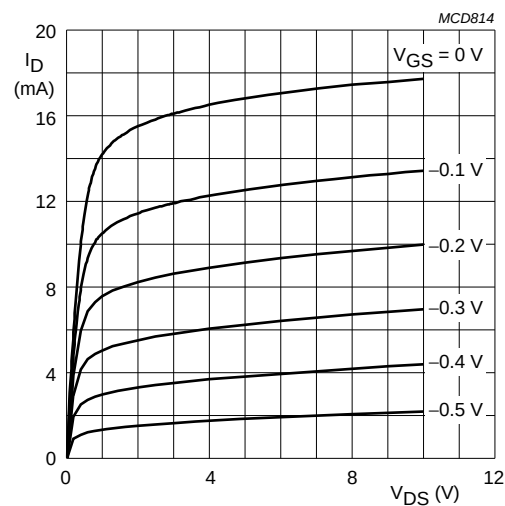
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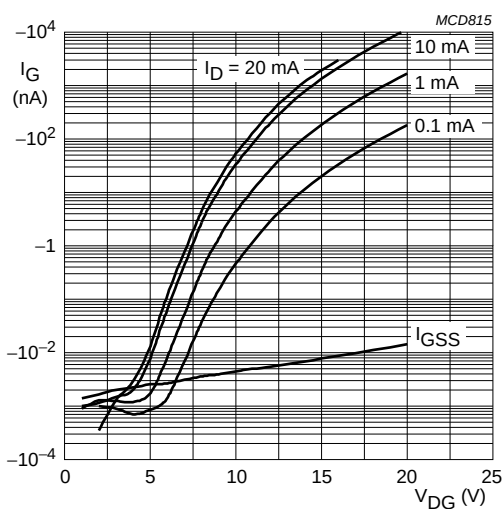
$V_{DS} = 8\text{ V}$; $T_j = 25\text{ }^{\circ}\text{C}$.

Fig.7 Drain current as a function of gate-source voltage; typical values.



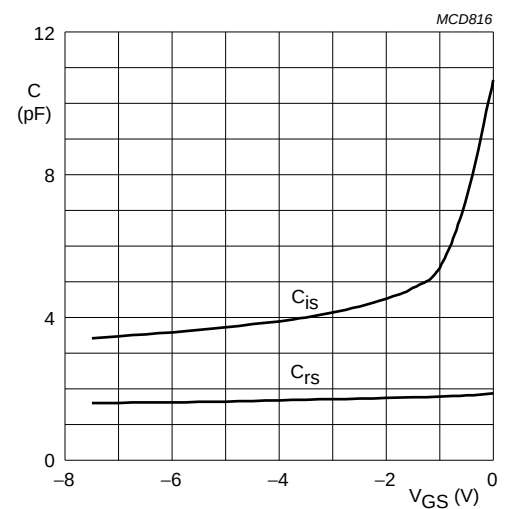
$V_{DS} = 8\text{ V}$; $T_j = 25\text{ }^{\circ}\text{C}$.

Fig.8 Drain current as a function of drain-source voltage; typical values.



$V_{DS} = 8\text{ V}$; $T_j = 25\text{ }^{\circ}\text{C}$.

Fig.9 Gate current as a function of drain-gate voltage; typical values.

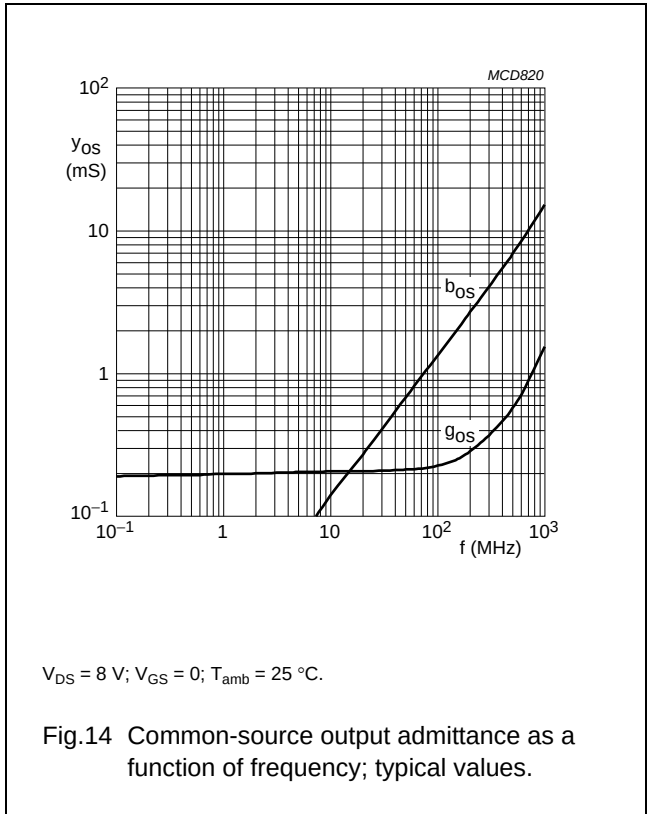
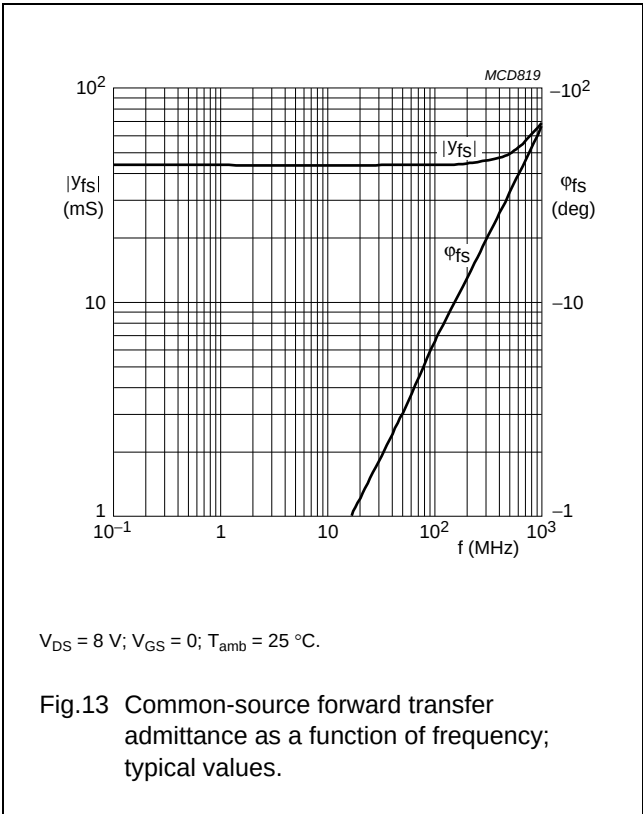
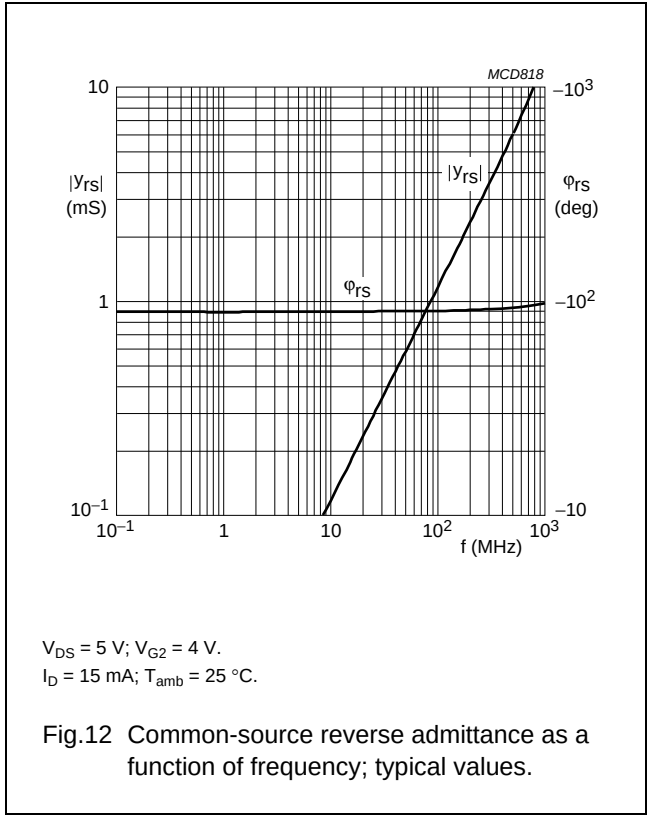
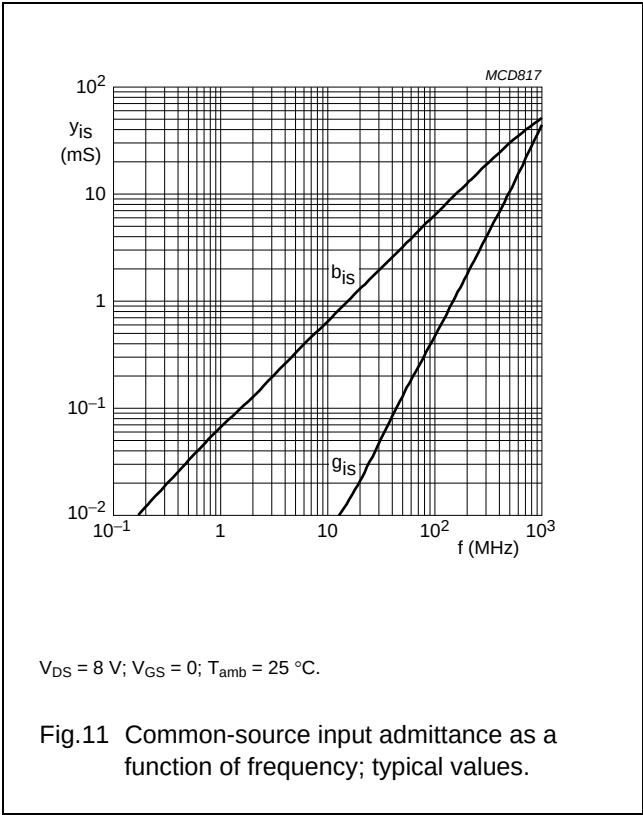


$V_{DS} = 8\text{ V}$; $f = 1\text{ MHz}$; $T_j = 25\text{ }^{\circ}\text{C}$.

Fig.10 Input and reverse transfer capacitance as functions of gate-source voltage; typical values.

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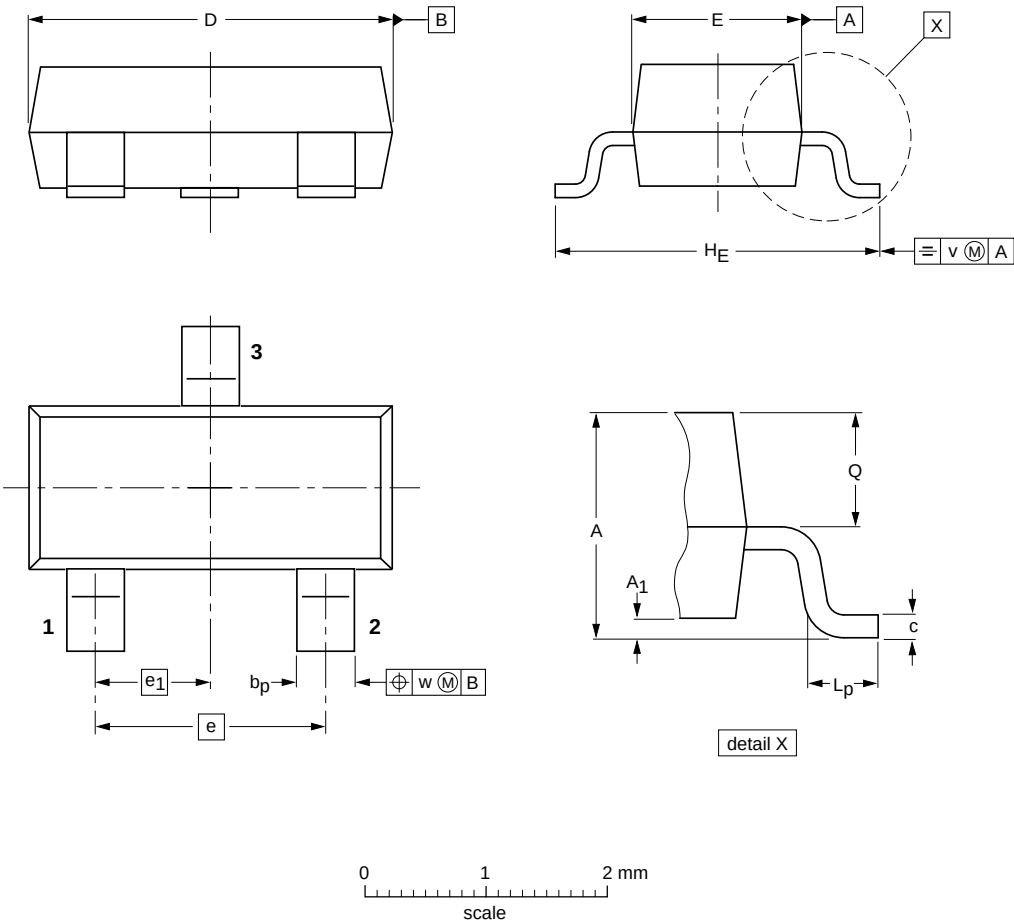
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PACKAGE OUTLINE

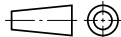
Plastic surface-mounted package; 3 leads

SOT23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT23		TO-236AB				04-11-04 06-03-16

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Contact information

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